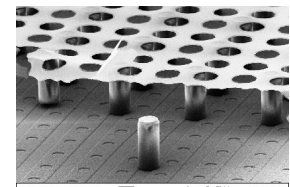
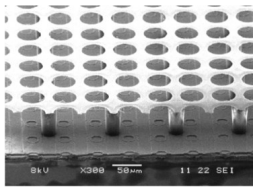


# GridPix as a candidate for the future of CAST

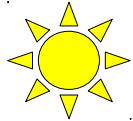
C. Krieger, J. Kaminski, Y. Bilevych,  
T. Krautscheid, K. Desch

University of Bonn

6<sup>th</sup> TPC-Symposium  
Paris  
17. - 19. December 2012

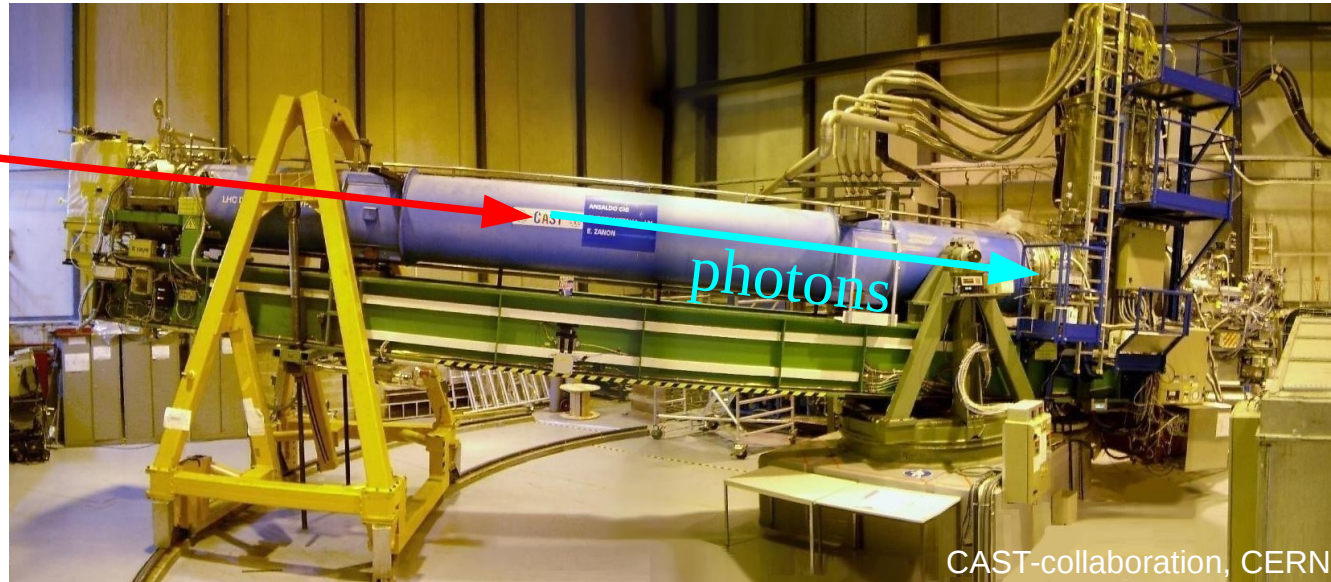


# Axion Search with CAST



axions

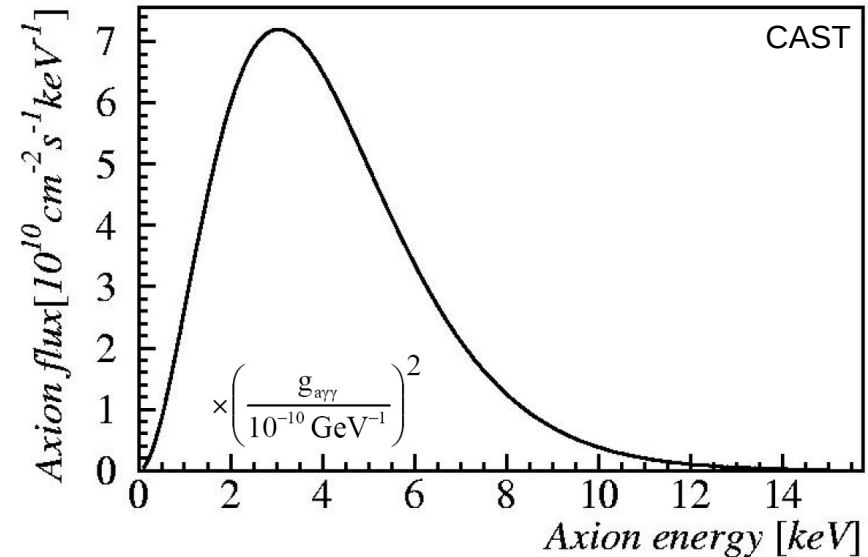
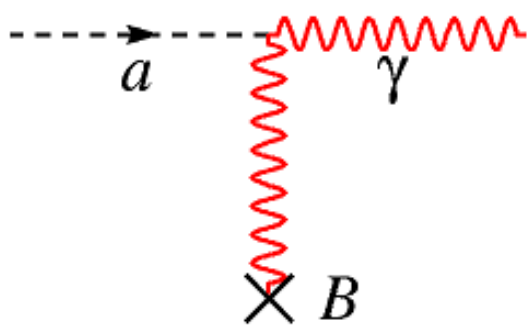
Decommissioned LHC-magnet is pointed to the sun. Axions produced in the sun convert into X-ray photons.

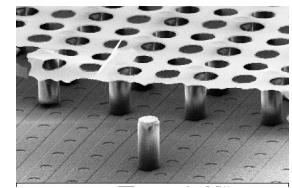
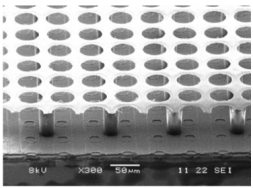


CAST-collaboration, CERN

Detect X-ray photons with high efficiency.

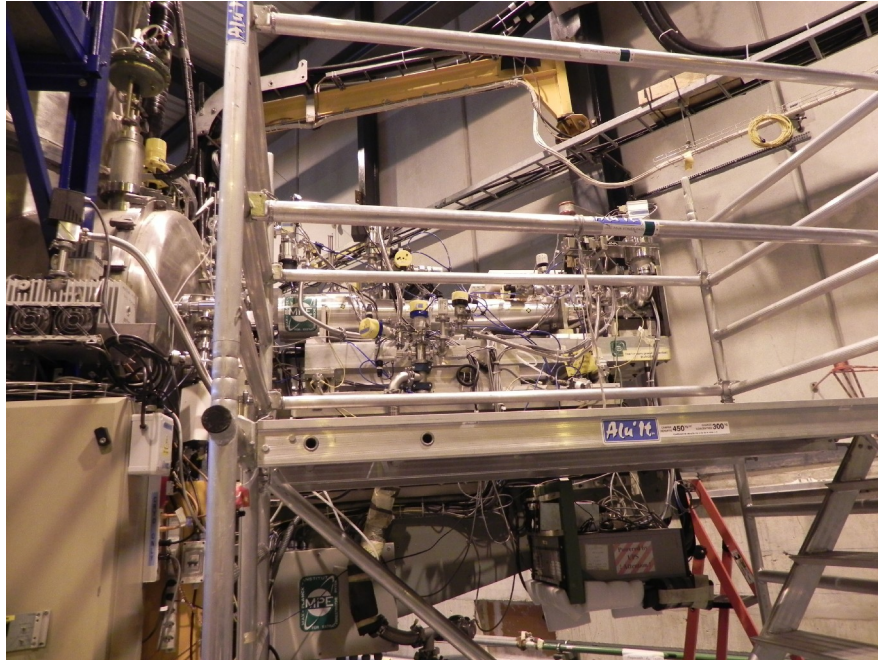
→ Gaseous detectors (Micromegas) with Ar-mixture at 1-2 bar over-pressure (and 1 CCD).





# Reduction in Background

Suppress background as much as possible to increase signal significance



Spare X-ray telescope from ABRIXAS space mission

- 27 nested gold coated nickel shells
  - focal length 1.7 m
  - 35% transmission
  - diameter 43 mm (magnet)
  - focused to 3 mm diameter
- => background reduced by factor 200  
by reducing area and concentrating  
signal on smaller area

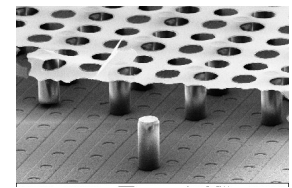
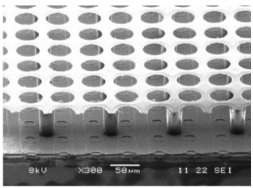
Several layers of shielding to reduce background

Better reconstruction of the events

→ improve energy and spatial resolution of detector

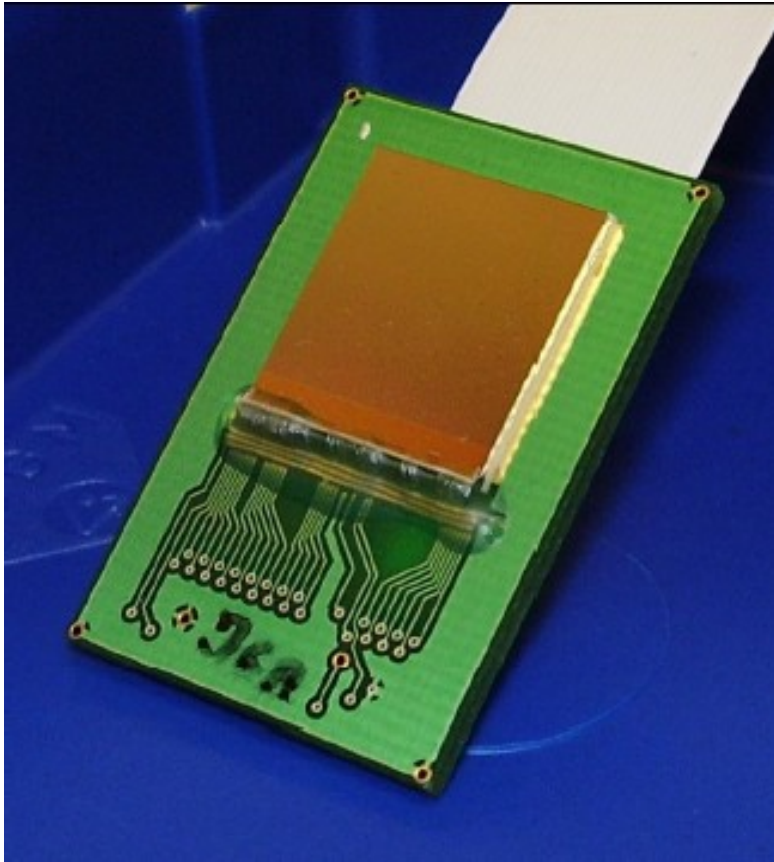
Micromegas have a very good intrinsic resolution,  
but it is often limited by large readout pads.

=> Decrease pad size to improve detector resolution.



# Timepix Chip

Timepix chip (1<sup>st</sup> version) derived from MediPix-2



Available for tests since Nov. 2006

Number of pixel:  $256 \times 256$  pixel

Pixel pitch:  $55 \times 55 \mu\text{m}^2$

Chip dimensions:  $1.4 \times 1.4 \text{ cm}^2$

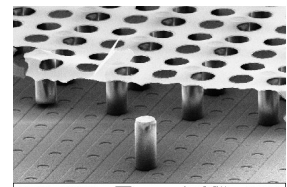
ENC:  $\sim 90 e^-$

Each pixel can be set to one of these modes:

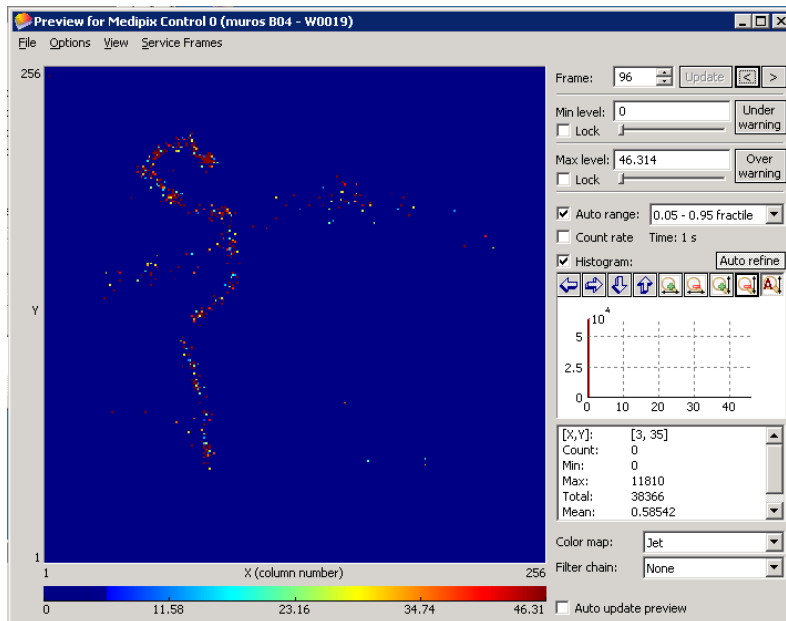
- Hit counting
- TOT = time over threshold  
gives integrated charge
- Time between hit and shutter end
- Hit/no-hit

Limitations: no multi-hit capability, charge and time measurement not possible for one pixel

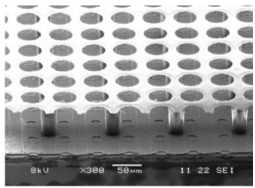
The successor Timepix-3 is being designed and will be submitted soon.



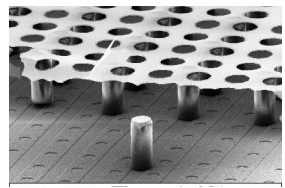
MUROS 2.1 designed at NIKHEF -  
not in production anymore



Data acquisition was operated  
by the Pixelman software  
developed at the TU Prague.



# Production of InGrids



The production of InGrids was pioneered by the University of Twente/MESA+.



1. Dicing of Wafer



2. Formation of  $\text{Si}_x\text{N}_y$  protection layer



3. Deposition of SU-8



4. Pillars-like structure formation



5. Deposition of thin Al layer

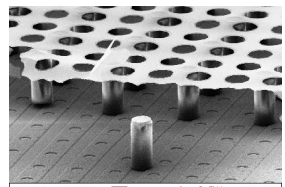
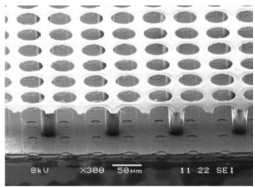


6. Formation of Al grid



7. Development of SU-8

Grid holes aligned with the readout pads.



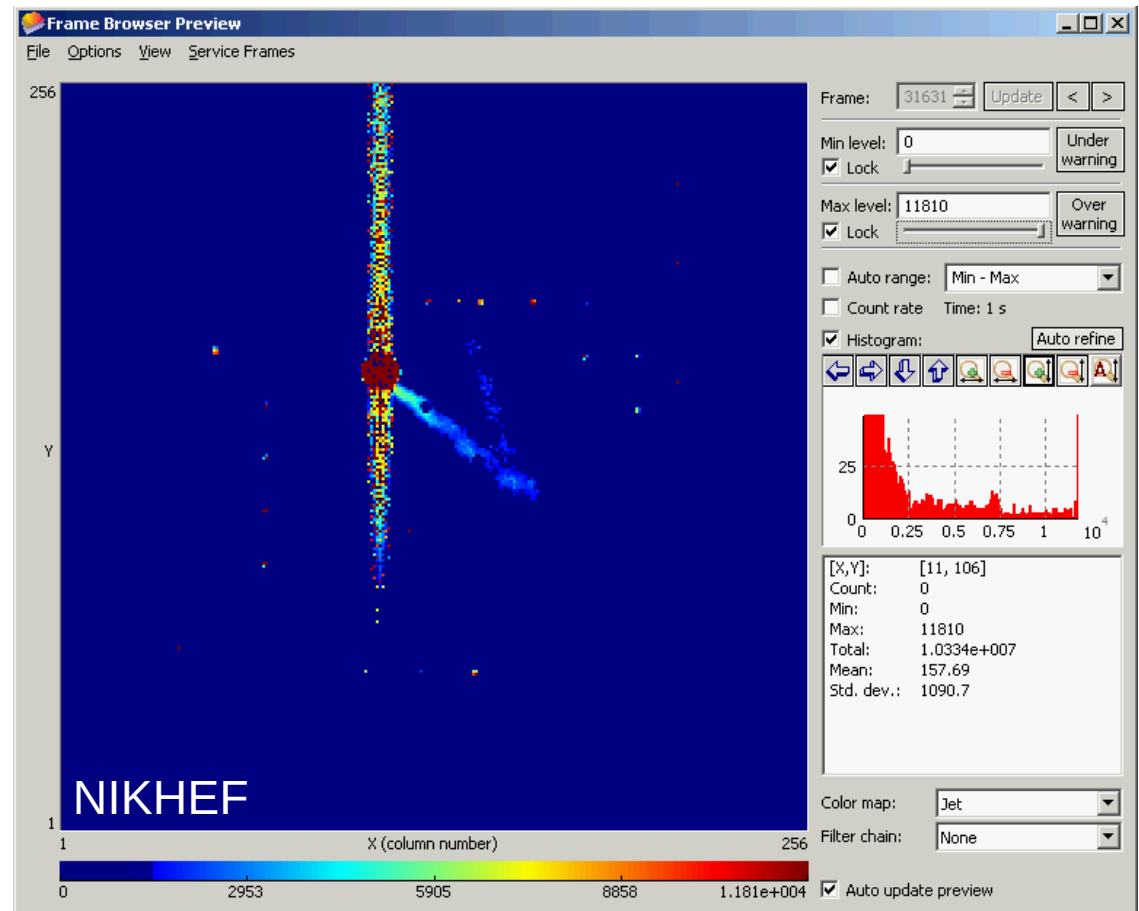
**Discharge** triggered for example by highly ionizing particles could easily **destroy the the chip**. The charge collected by one pixel was too high.

A protection layer is placed on the chip to **disperse the charge** on many pixels and thus lower the input current per pixels. Besides, the charge is removed slowly and thus **quenches the discharge**.

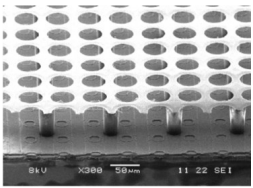
high resistive material

15  $\mu\text{m}$  aSi:H ( $\sim 10^{11} \Omega\cdot\text{cm}$ )

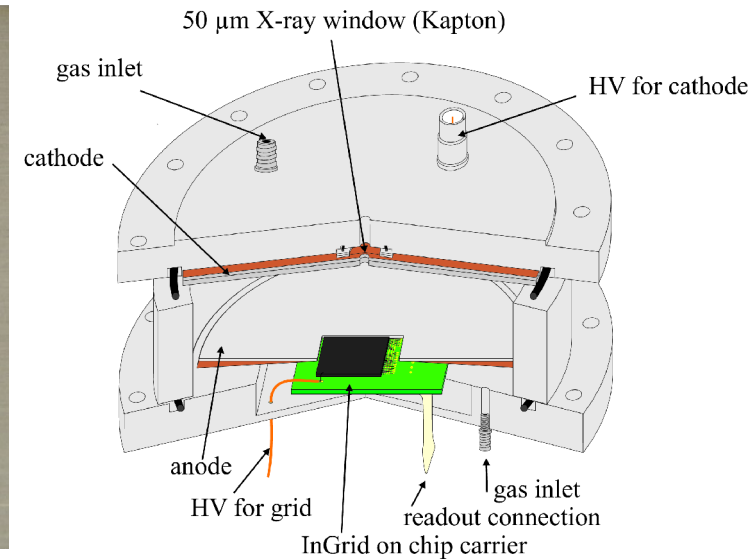
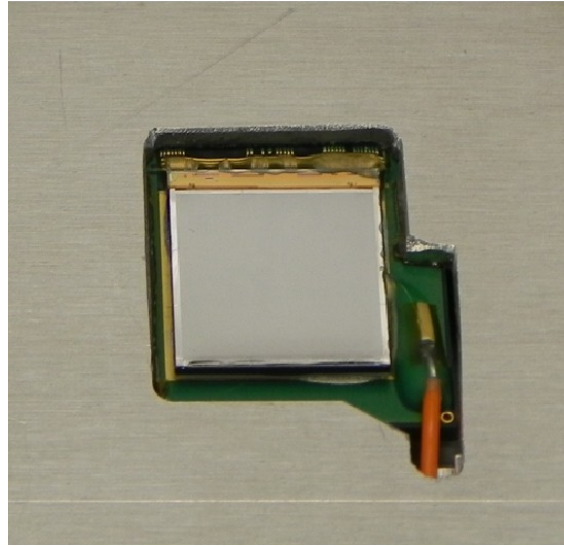
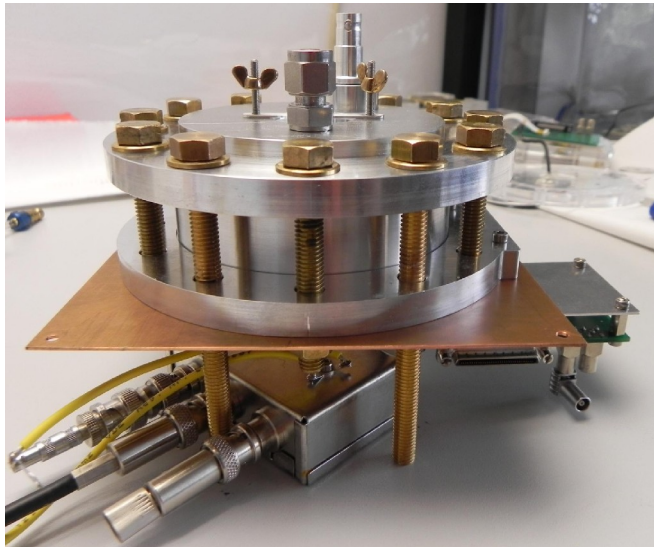
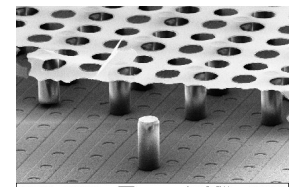
8  $\mu\text{m}$  Si<sub>X</sub>N<sub>Y</sub> ( $\sim 10^{14} \Omega\cdot\text{cm}$ )



Chips survives several thousand discharges triggered by  $\alpha$ s.

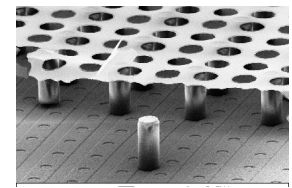
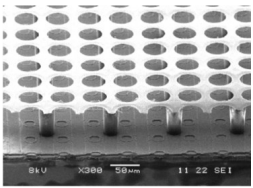


# First GridPix Detector

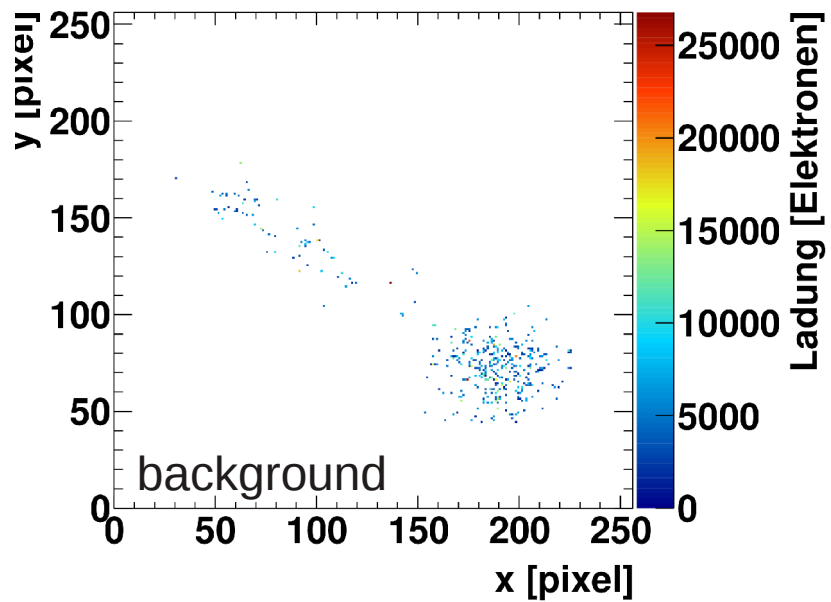
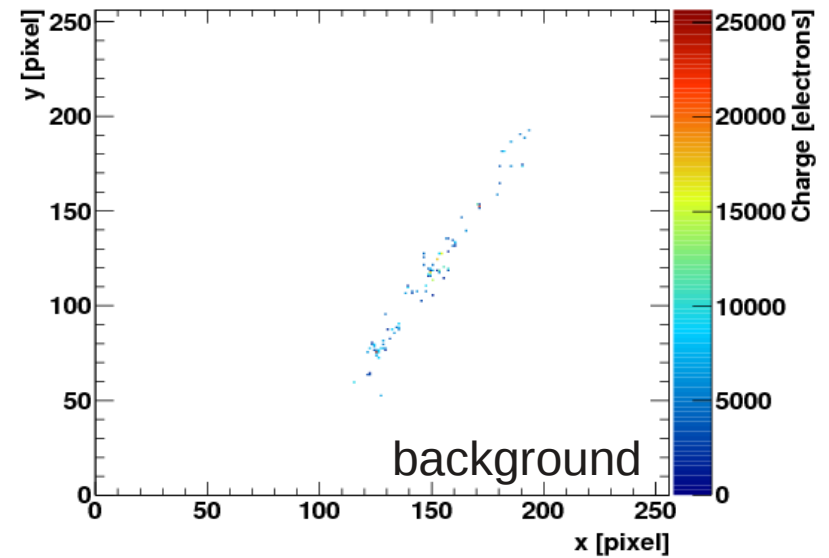
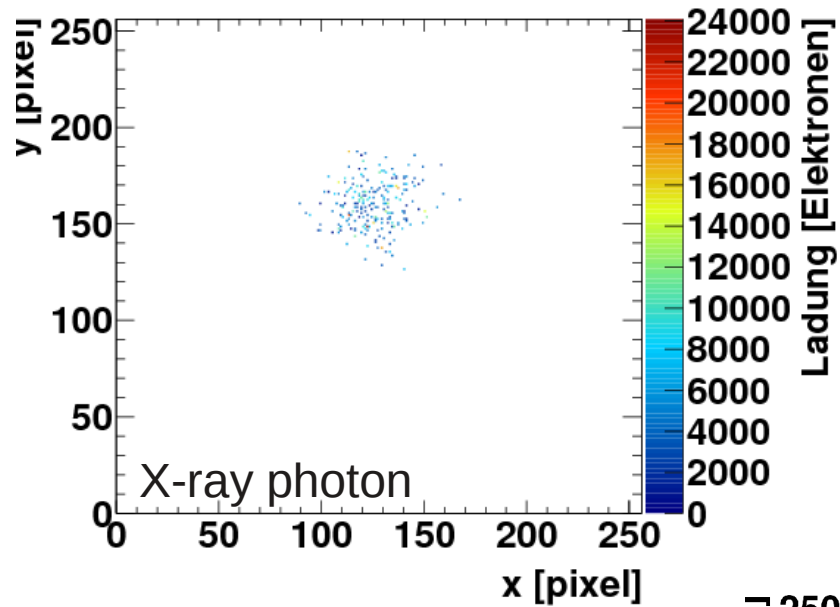


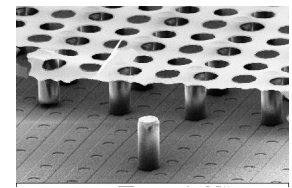
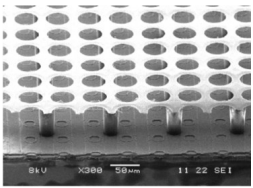
- Inner diameter 8 cm, maximum drift distance 2 cm
- Detector made of aluminum, insulation with Kapton<sup>®</sup>-foil
- Read out by one InGrid
- Entrance window diameter 1 mm, covered with 50 µm Kapton-foil
- Gas mixture Ar/iC<sub>4</sub>H<sub>10</sub> 95/5 (flux 2 l/h)  
only a few mbar over-pressure





# Example Events





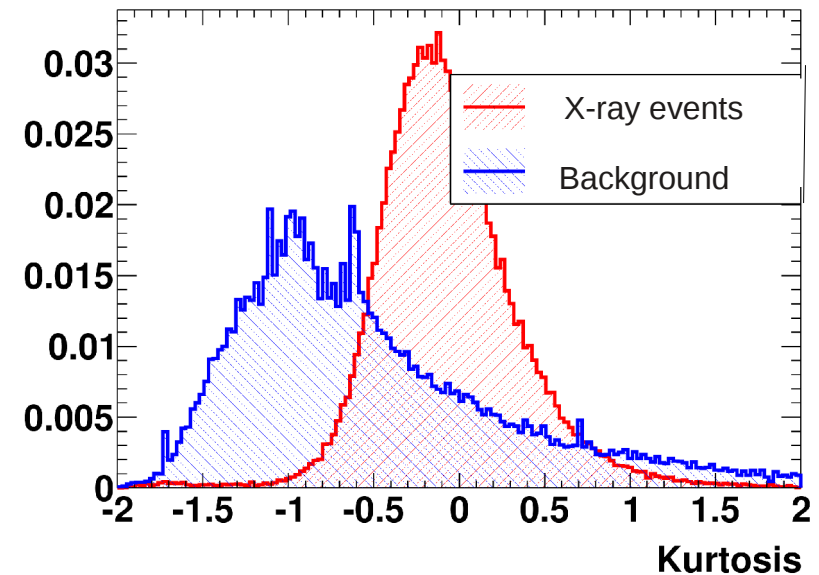
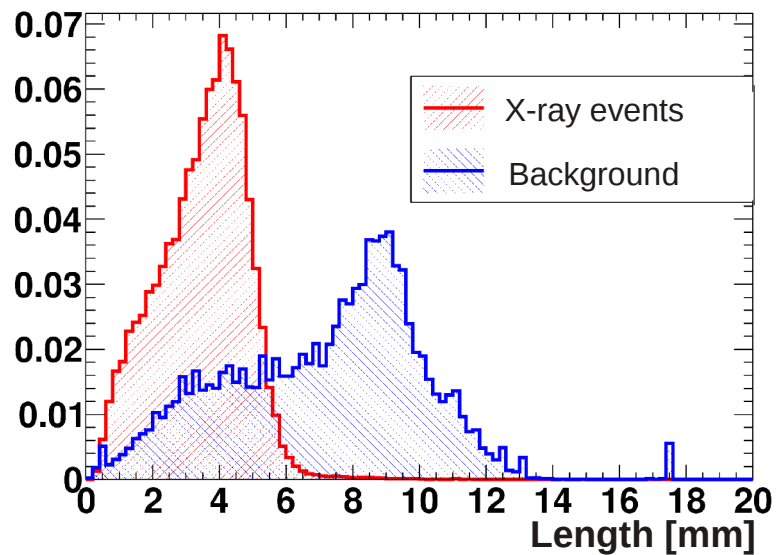
# Analysis

Event shapes are reconstructed under the assumption being either a track or an X-ray photon.

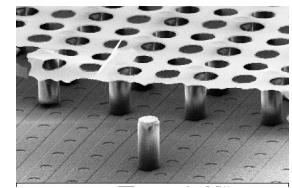
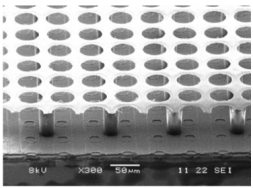
Event shapes are determined under both assumptions for each event.

(e.g. widths and higher central moments along the longest and shorted axes)

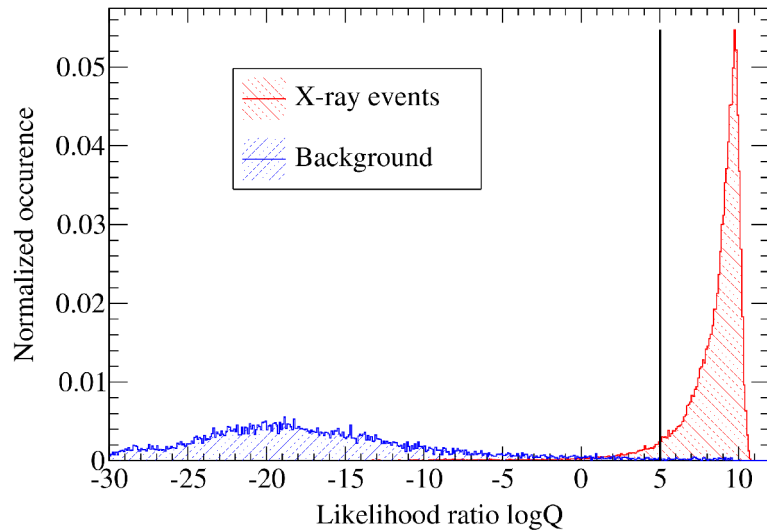
The values are then compared to sample distributions for both hypothesis:



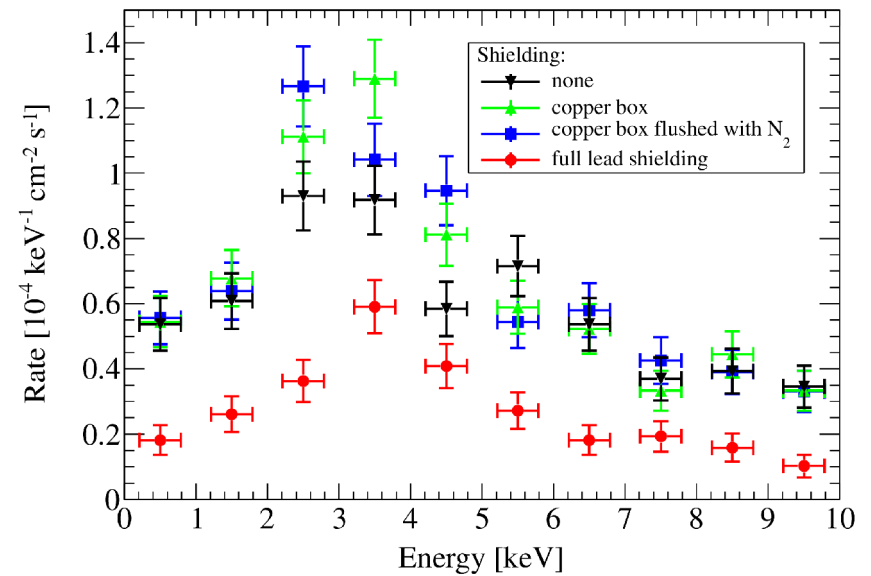
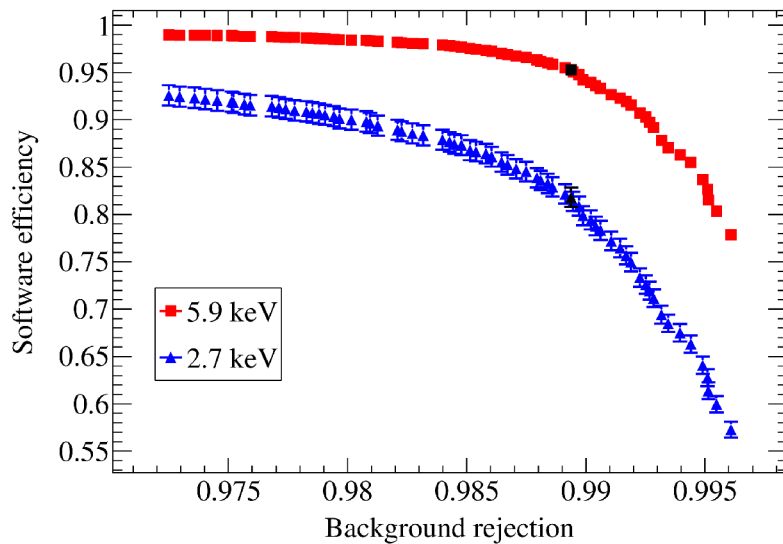
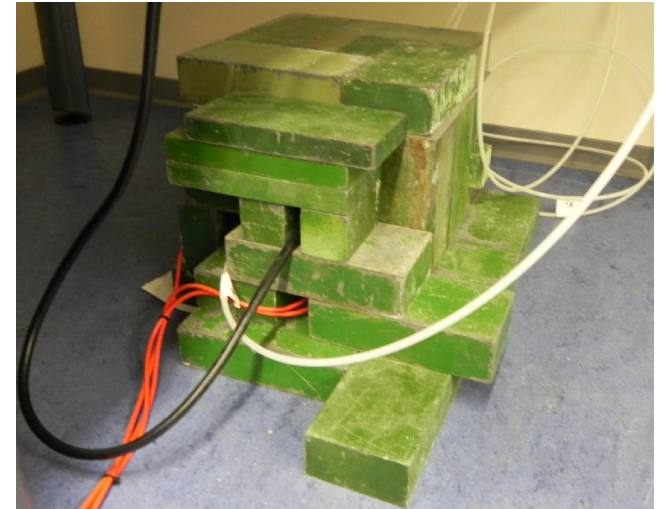
A likelihood ratio based on 6 observables is used to make an event-by-event decision.

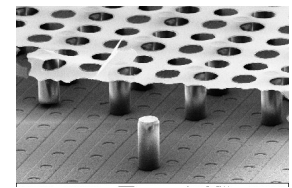
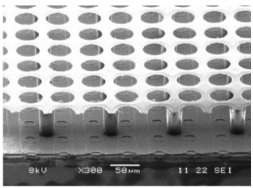


# Background Reduction



Lead shielding and likelihood ratio algorithm suppress background down to  $10^{-5} \text{ keVcm}^{-2}\text{s}^{-1}$





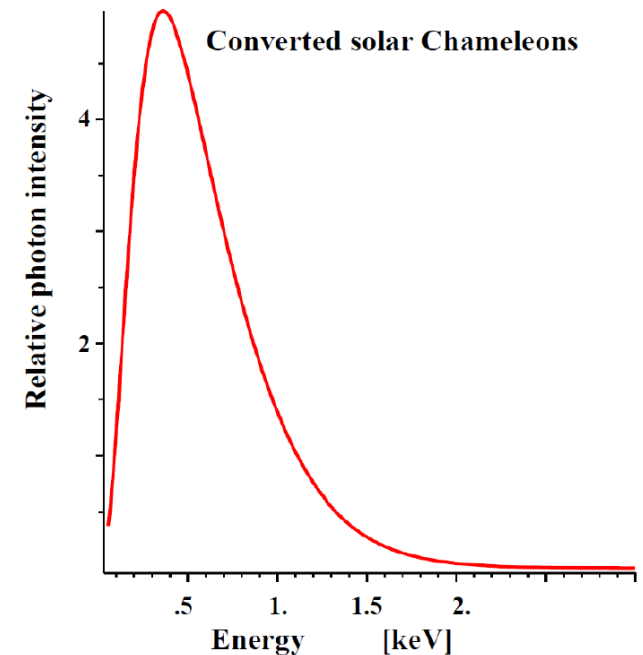
# Further Work

## In progress

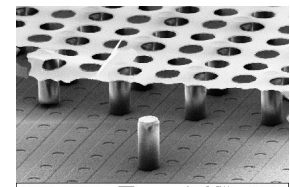
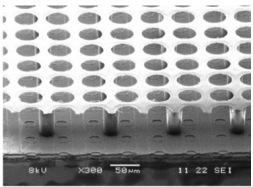
- Design of new detector –  
compatible with other Micromegas detectors
- Production of new InGrids
- New electronics
- Entrance windows with maximal transmission

## In close future

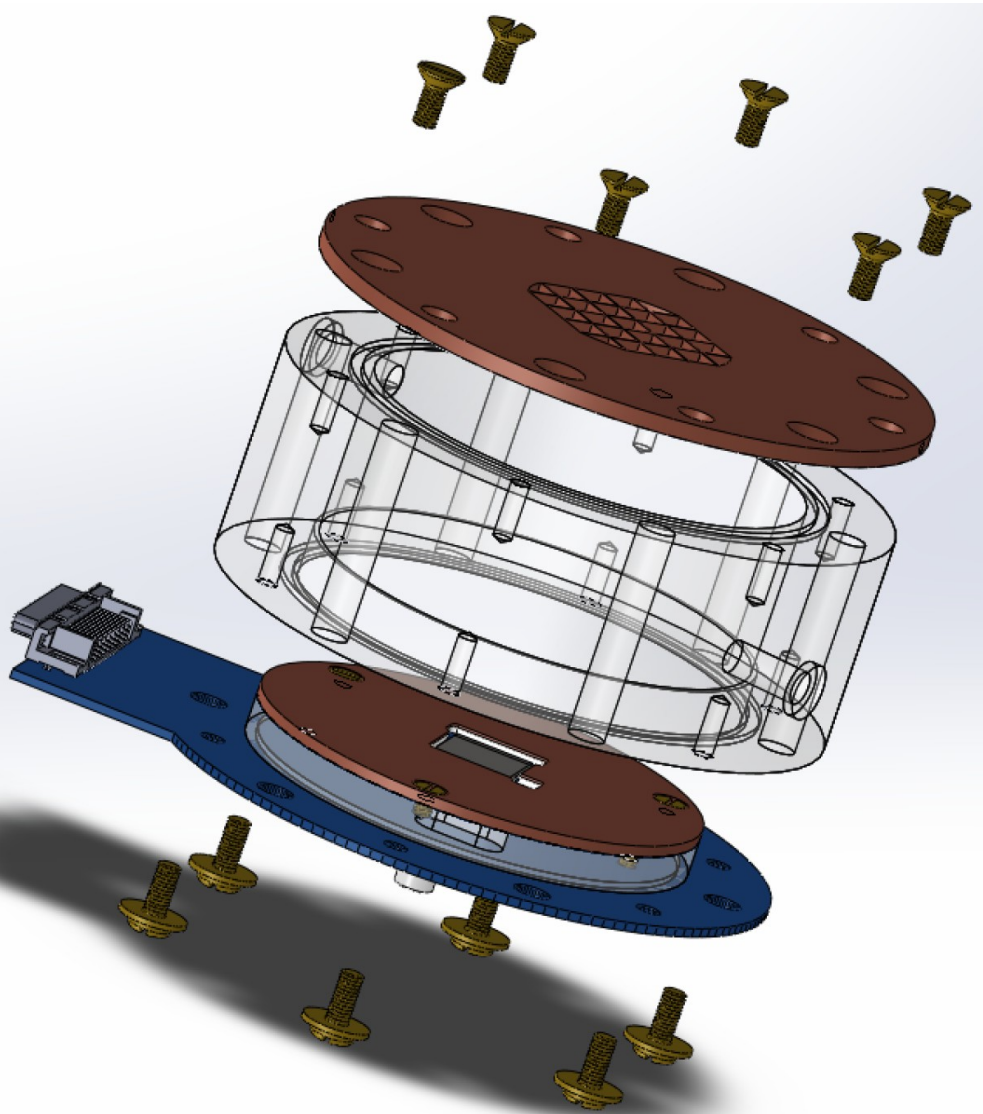
- Connection to telescope
- Study of the lower detection limit  
for searches of chameleons  
(software efficiency of reconstruction and  
entrance window transmission)
- Decouple grid signal and sample with FADC  
→ further reduction of background



CAST report SPSC-107



# Design of new Detector



Removed all of the aluminum.

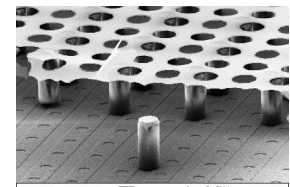
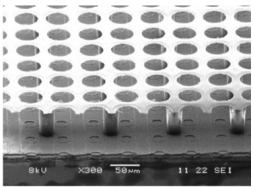
Detector is made of acrylic glass and copper.

All connection compatible with CAST.

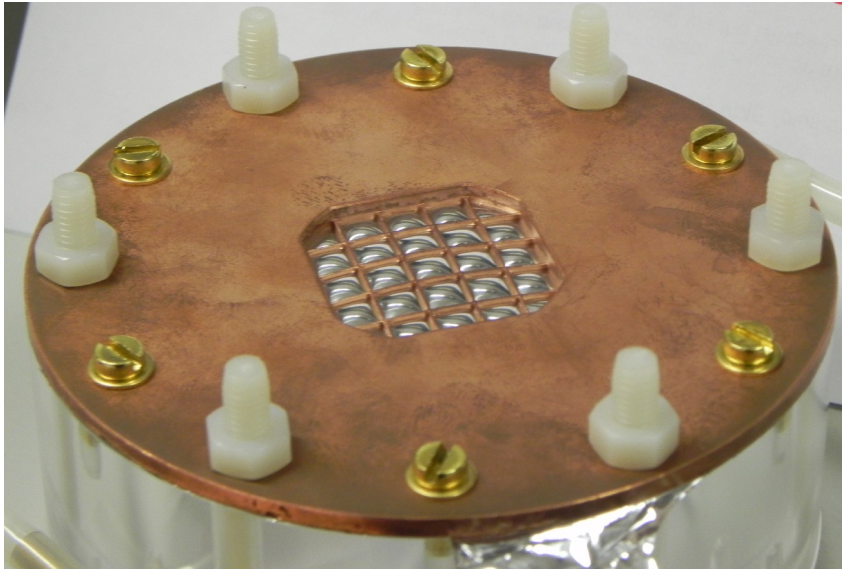
Larger entrance window with strongback (optical transparency  $\sim 90\%$ ).

2 drift cylinders (2-3 cm drift distance).

Detector design follows closely current Micromegas detectors.



# Entrance Windows



Several strongbacks have been produced to test different windows.

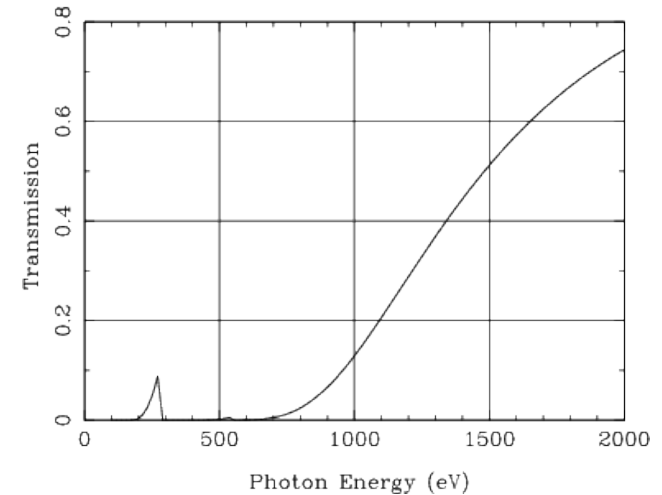
First test with a 5  $\mu\text{m}$  Mylar-foil  
→ stood an over-pressure of 1.5 bar



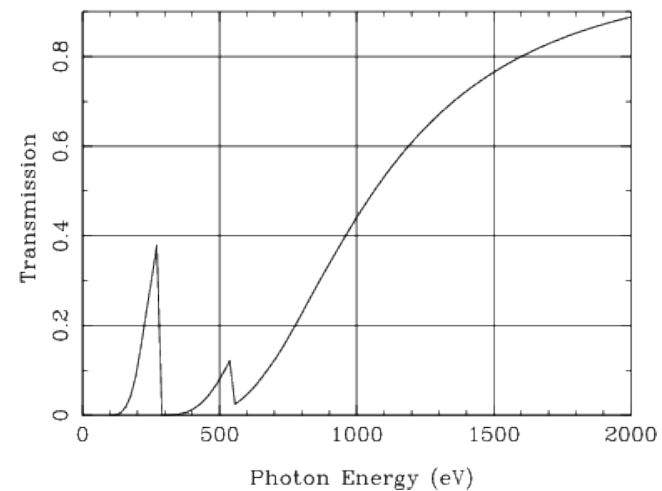
Transmission not good enough.

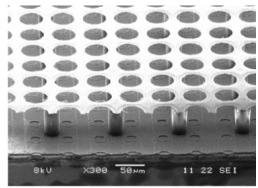
Next test with a 2  $\mu\text{m}$  Mylar-foil.

C10H804 Density=1.4 Thickness=5. microns

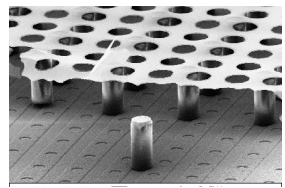


C10H804 Density=1.4 Thickness=2. microns

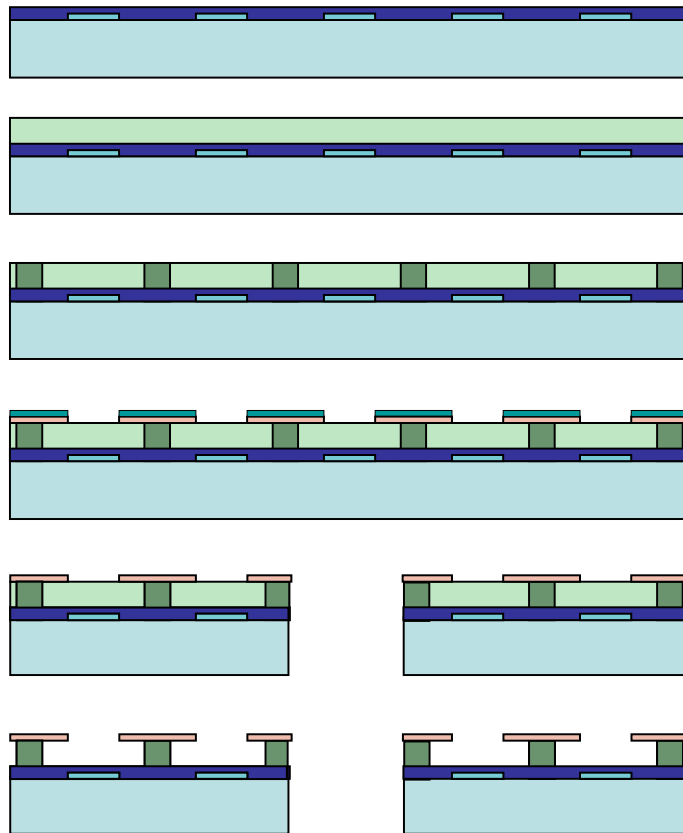




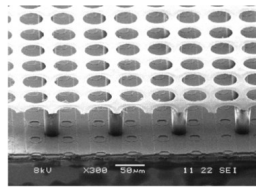
# Wafer-based Production Fraunhofer IZM



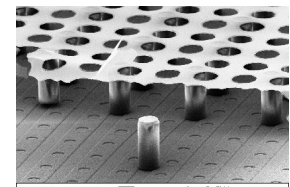
Production at Twente was based on 1 - 9 chips process.  
This could not satisfy the increasing demands of R&D projects.  
New production set up at the Fraunhofer Institut IZM at Berlin.  
This process is wafer-based → 1 wafer (107 chips) is processed at a time.



1. Formation of  $\text{Si}_x\text{N}_y$  protection layer
2. Deposition of SU-8
3. Pillar structure formation
4. Formation of Al grid
5. Dicing of Wafer
6. Development of SU-8



# Wafer-based Production



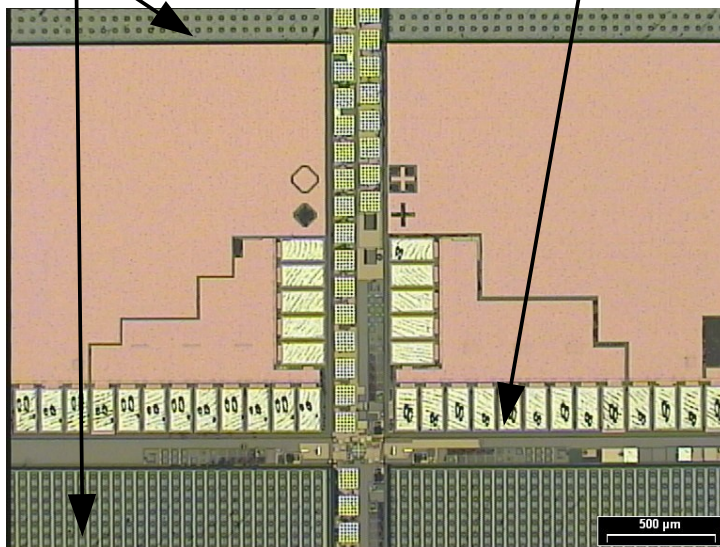
Main challenges: - Formation of layers, in particular protection layer

## MESA+

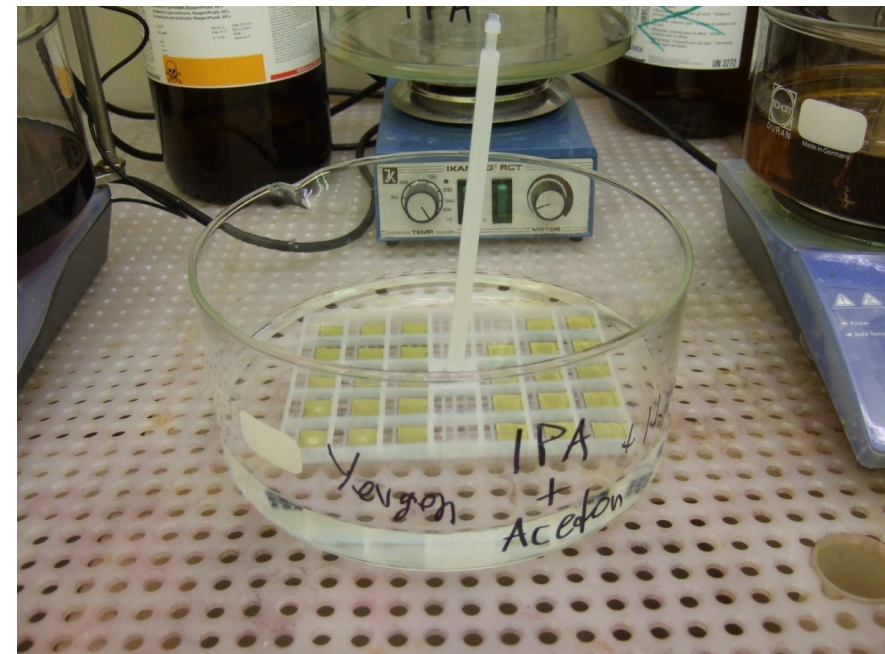
Institute for Nanotechnology

- Deposition of Al
- Final development of SU-8 → still chip-based

SiRN should not cover bond pads



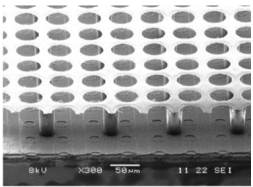
After development of pillars, the grid is too fragile for dicing



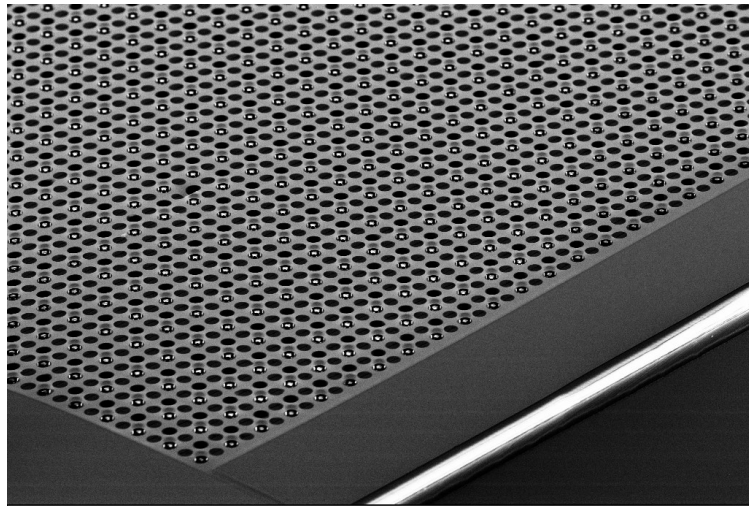
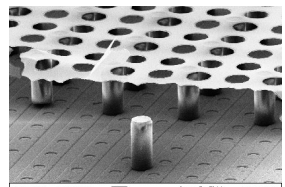
First tests: **mechanical mask**  
→ failed due to thermal stress  
Better: **polyimide mask** chem. removed

Time consuming

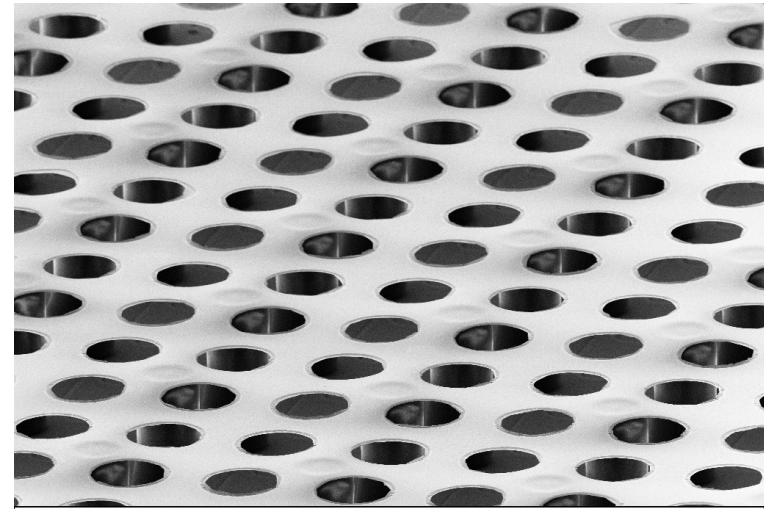




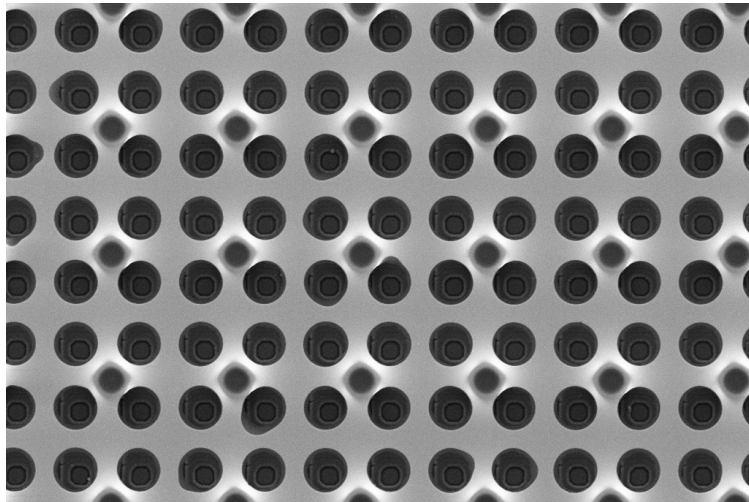
# SEM Pictures



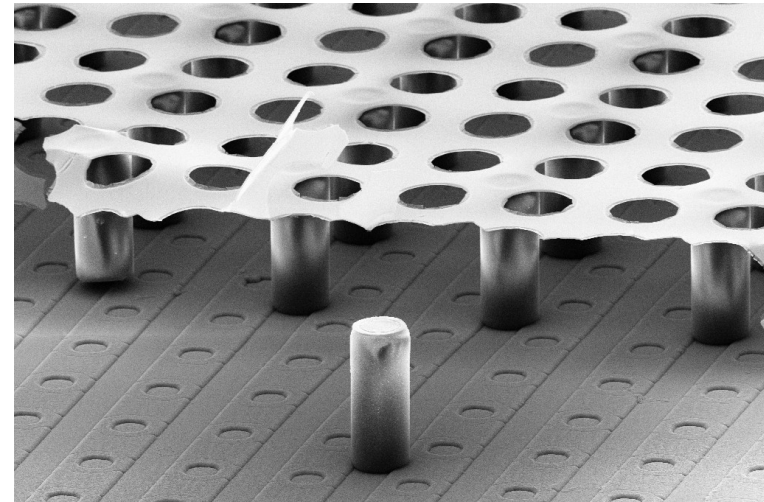
Mag = 58 X    Signal A = SE2    200µm    Stage at T = 60.0 °    Fraunhofer IZM  
WD = 19 mm    EHT = 20.00 kV    Chamber = 7.43e-004 Pa



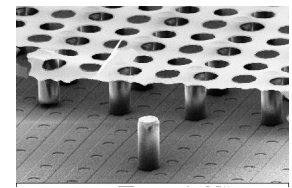
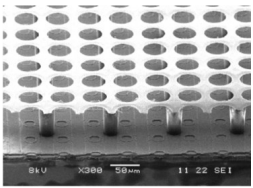
Mag = 324 X    Signal A = SE2    20µm    Stage at T = 70.1 °    Fraunhofer IZM  
WD = 18 mm    EHT = 20.00 kV    Chamber = 4.07e-004 Pa



Mag = 174 X    Signal A = SE2    100µm    Stage at T = 0.0 °    Fraunhofer IZM  
WD = 8 mm    EHT = 20.00 kV    Chamber = 1.31e-003 Pa

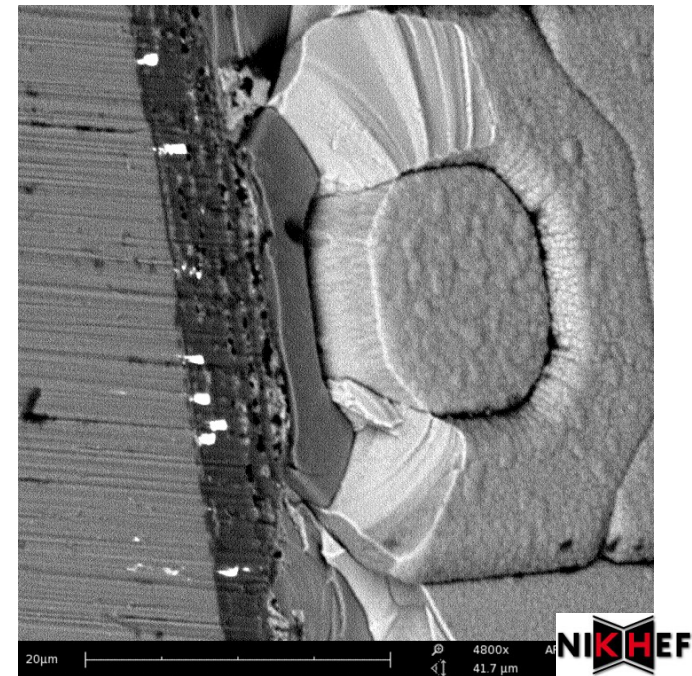
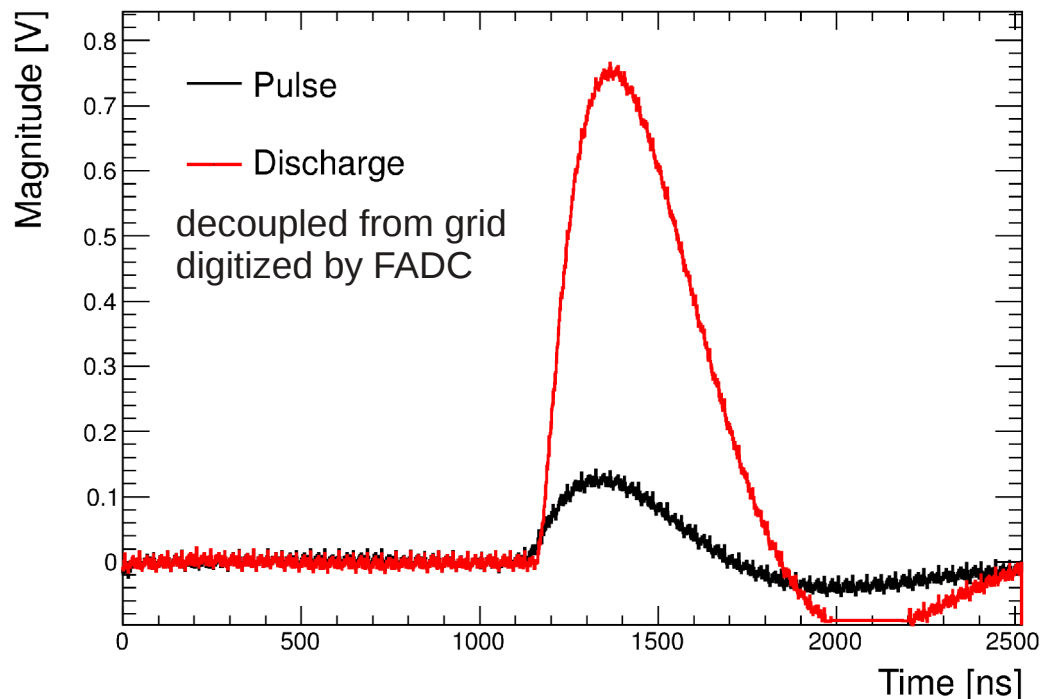


Mag = 303 X    Signal A = SE2    20µm    Stage at T = 70.1 °    Fraunhofer IZM  
WD = 18 mm    EHT = 20.00 kV    Chamber = 7.23e-004 Pa

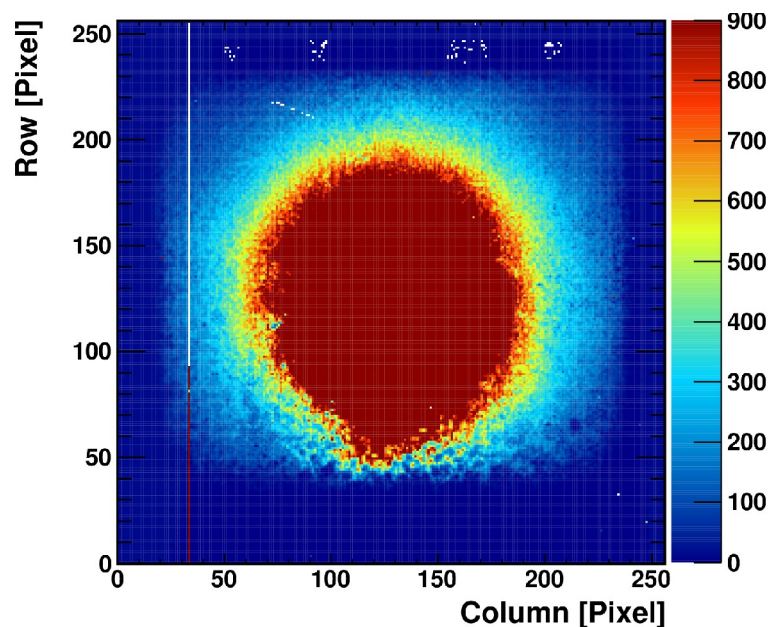
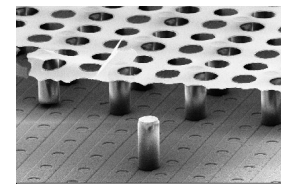
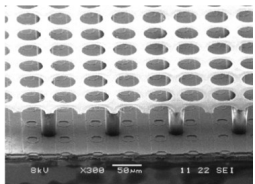


# Performance

1. batch (10/2011): Problems with resistive layer and Al-grid
2. batch: InGrids worked well, good energy resolution ( $\sigma_E/E \sim 7\%$ )  
(12/2011) Resistive layer proved vulnerable (chips died after 2 weeks)
3. batch: Chips survived many thousand X-ray-induced sparks  
(9/2012) But 7 out of 10 chips died in a hadronic test beam at CERN
4. batch: In preparation, 4 wafers with different resistive layer thicknesses



# Some Results from the 3. Batch



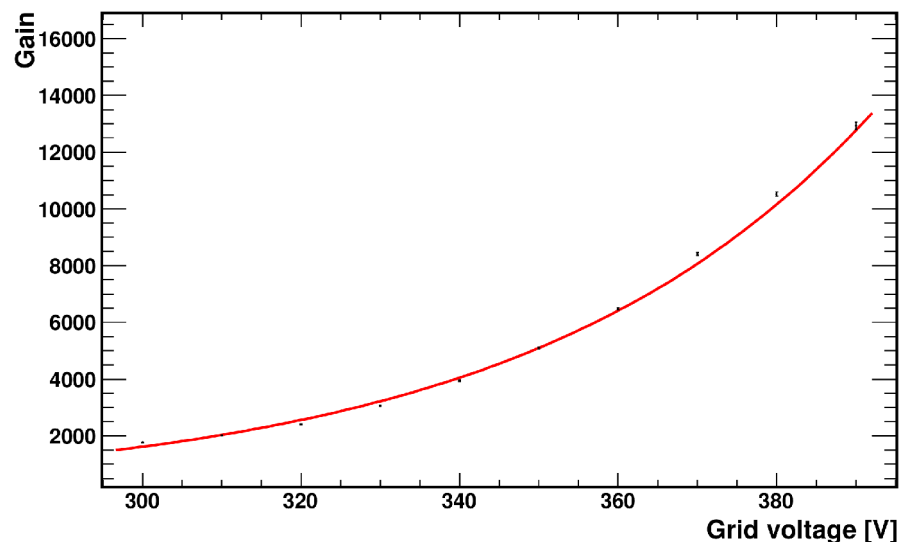
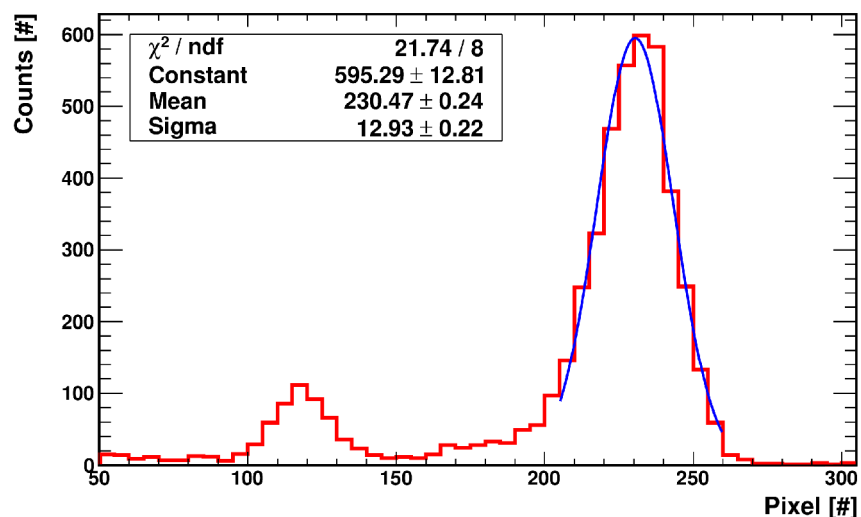
Occupancy plot shows very few closed holes

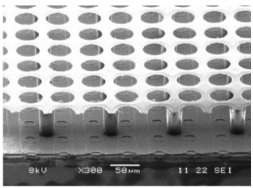
Energy resolution is similarly good as before:

$$\sigma_E/E = 5.5\% \text{ for the pixel spectrum}$$

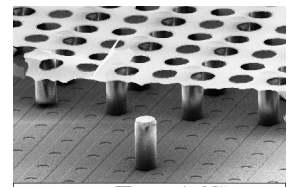
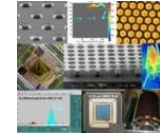
$$\sigma_E/E = 7.2\% \text{ for charge spectrum}$$

Voltages of 450 V could be applied to grid  
→ chip not destroyed.





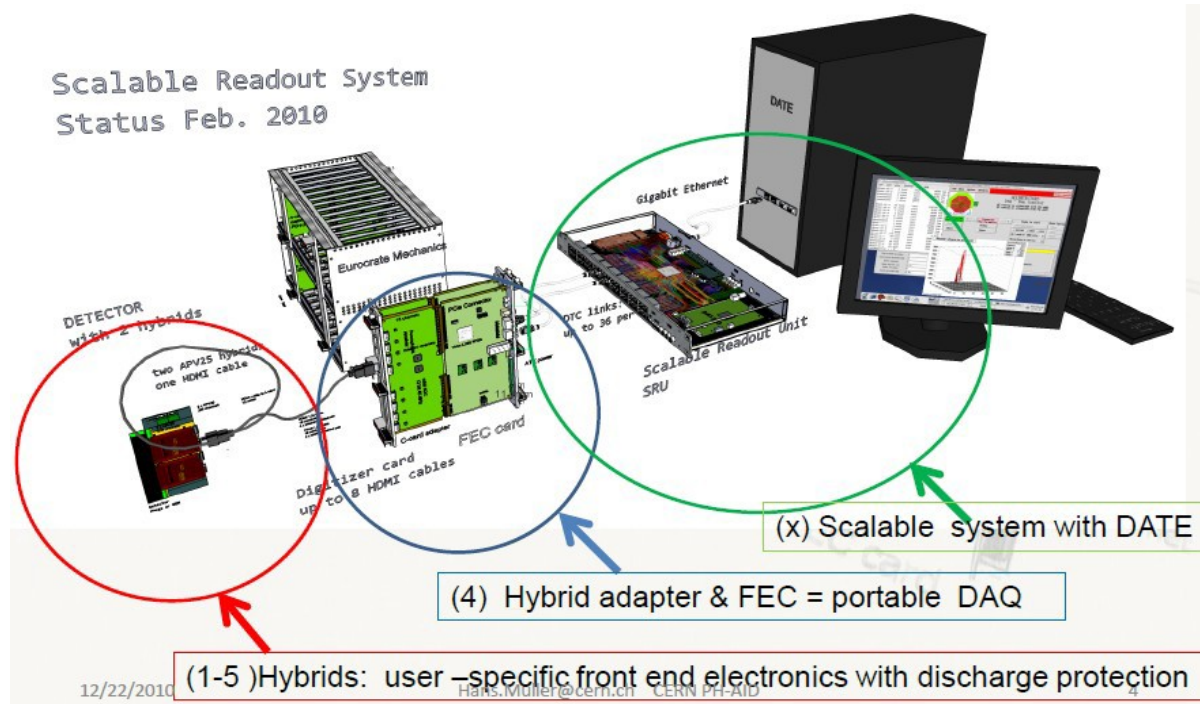
# Timepix readout with SRS



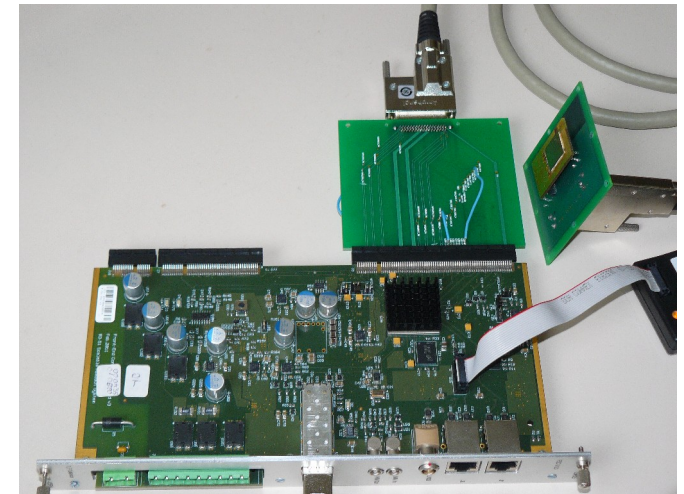
The Scalable Readout System is designed by the RD51 collaboration with CERN as a main developer.

Idea: produce a flexible readout electronics, which can handle different chips (new FPGA code, chip carrier), which many groups can use.

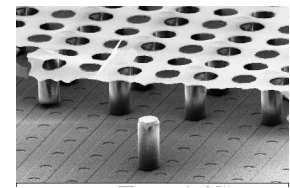
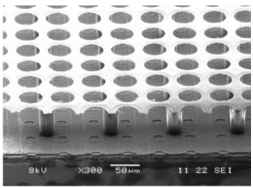
Scalable Readout System  
Status Feb. 2010



U. Bonn and U. Mainz are developing a readout for the Timepix chip



Operation has been demonstrated for a single and is being extended to multi-chip boards. A readout system based on this development will be used in CAST.



# Summary and Outlook

**GridPix detector shows an excellent performance:**

Energy resolution of  $\sigma_E/E \sim 5\%$  (at 5.9 keV)

Event shape analysis very effective in suppressing background.

Further optimization is planned.

Study of entrance window transmission has started.

Installation in CAST is planned for June 2013.

**Production techniques of InGrids are well advanced,**  
but resistive layer may have to be optimized a bit.

**New readout system** optimized for large systems and flexibility has been developed.

New Timepix-3 should be available next year and will be used as soon as possible.